MN39143FT

6 mm (type-1/3) High-sensitivity CCD Area Image Sensor

■ Overview

The MN39143FT is a 6 mm (type-1/3) interline transfer CCD (IT-CCD) solid state image sensor device.

This device uses photodiodes in the optoelectric conversion section and CCDs for signal readout. The electronic shutter function has made an exposure time of 1/10 000 seconds possible. Further, this device has the features of high sensitivity, low noise, broad dynamic range, and low smear.

This device has a total of 403 920 pixels (816 horizontal \times 495 vertical) and provides stable and clear images with a resolution of 480 horizontal TV-lines and 350 vertical TV-lines.

Part Number Size		System	Color or B/W		
MN39143FT	6 mm (type-1/3)	NTSC	Color		

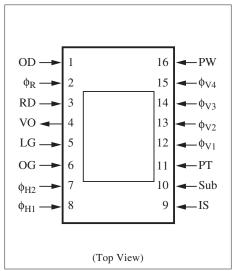
Features

- Total number of pixels: 816 (horizontal) × 495 (vertical)
- High sensitivity
- Broad dynamic range (compared to our conventional CCD ×1.2)
- Low smear
- Electronic shutter
- No image distortion
- Small size enables design of compact equipment
- · High reliability

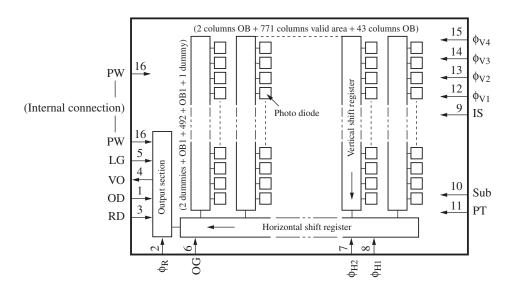
Applications

• Camcorders, surveillance cameras, door cameras

■ Pin Assignments



■ Block Diagram



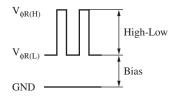
■ Pin Descriptions

Pin No.	Symbol	Description	Pin No.	Symbol	Description
1	OD	Output drain	9	IS	Horizontal CCD input source
2	φ _R	Reset pulse	10	Sub	Substrate
3	RD	Reset drain	11	PT	P-well for protection circuit
4	VO	Video output	12	$\phi_{\mathrm{V}1}$	Vertical shift register clock pulse 1
5	LG	Output load transistor gate	13	ϕ_{V2}	Vertical shift register clock pulse 2
6	OG	Output gate	14	φ _{V3}	Vertical shift register clock pulse 3
7	ф _{H2}	Horizontal register clock pulse 2	15	ϕ_{V4}	Vertical shift register clock pulse 4
8	ф _{Н1}	Horizontal register clock pulse 1	16	PW	P-well

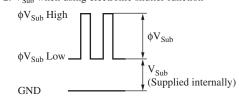
■ Absolute Maximum Ratings and Operating Conditions

Parameter			Rating		Operating condition				
		Symbol	Min	Max	Min	Тур	Max	Unit	
Reset drain voltage	e	$V_{ m RD}$	- 0.2	18.0	14.5	15.0	V		
Output drain volta	ge	V _{OD}	- 0.2	18.0	14.5	15.0	15.5	V	
Output load transis gate voltage	stor	V_{LG}		(Internal bias)					
Output gate voltag	e	V _{OG}		V					
Horizontal CCD input	source voltage	V_{IS}	- 0.2	18.0	14.5	15.0	15.5	V	
Protection P-well	voltage	V _{PT} *3, 4	-9.0	0.2	-7.3	-7.0	-6.7	V	
P-well voltage		V_{PW}	Reference	e voltage	_	0	_	V	
Reset	High-Low	$V_{\phi R(H-L)}^{*1}$	_	5.0	3.0	3.3	3.6	V	
pulse voltage	Bias	$V_{\phi R(Bias)}^{*1}$						V	
Horizontal register		$V_{\phi H1(H)}$	_	5.0	3.0	3.3	3.6	V	
clock pulse voltage	e 1	$V_{\phi H1(L)}$	- 0.2	_	- 0.1	0	0.1	=	
Horizontal register		$V_{\phi H2(H)}$	_	5.0	3.0	3.3	3.6	V	
clock pulse voltage 2		$V_{\phi H2(L)}$	- 0.2	_	- 0.1	0	0.1		
Vertical shift regist	Vertical shift register		_	18.0	14.5	15.0	15.5	V	
clock pulse voltage 1		$V_{\phi V1(M)}$ *3, 4	_	_	- 0.2	0	0.2		
		V _{\phiV1(L)} *3, 4	-9.0	_	-7.3	-7.0	-6.7		
Vertical shift register		$V_{\phi V2(M)}$ *3, 4	_	15.0	- 0.2	0	0.2	V	
clock pulse voltage	elock pulse voltage 2		-9.0	_	-7.3	-7.0	-6.7		
Vertical shift regist	Vertical shift register		_	18.0	14.5	15.0	15.5	V	
clock pulse voltage 3		$V_{\phi V3(M)}$ *3, 4	_	_	- 0.2	0	0.2		
		V _{\phiV3(L)} *3, 4	-9.0	_	-7.3	-7.0	-6.7		
Vertical shift register		$V_{\phi V4(M)}$ *3, 4	_	15.0	- 0.2	0	0.2	V	
clock pulse voltage 4		V _{\phiV4(L)} *3, 4	-9.0	_	-7.3	-7.0	-6.7		
Substrate voltage		V _{Sub} *2	-0.2	45.0	Supplied internally		nally	V	
		φV _{Sub} *2]		21.0	22.0	23.0	1	
Operating tempera	ture	T_{opr}	-10	70	_	25	_	°C	
Storage temperatur	re	T_{stg}	-30	80	_	_	_	°C	

Note) *1: Reset



 $*2: V_{Sub}$ when using electronic shutter function



- *3: Absolute maximum rating $-0.2 < V_{\phi V} V_{PT} < 24.5 \text{ (V)}$
- *4: Relation between V_{PT} and $V_{\varphi V(L)}$

Set V_{PT} that is to meet the following conditions for VL voltage of the vertical shift clock waveform.

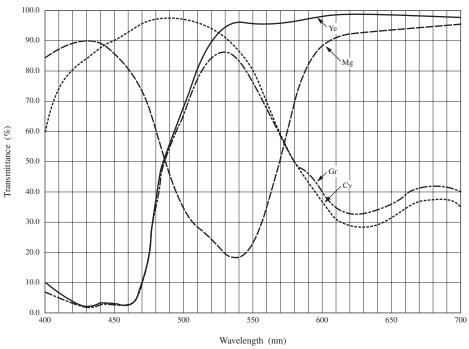
$$V_{PT} \le VL \ (V_{\phi V1L} \ to \ V_{\phi V4L})$$

■ Optical Characteristics

	Color	Effective		Saturation	Sensitivity	Vertical smear	Horizontal	Vertical
Part Number	or	pixels		output	F8	Sm	resolution	resolution
	B/W	Н	V	Typ (mV)	Typ (mV)	Typ (dB)	Typ (TV-lines)	Typ (TV-lines)
MN39143FT	Color	771	492	800	450	-100	480	350

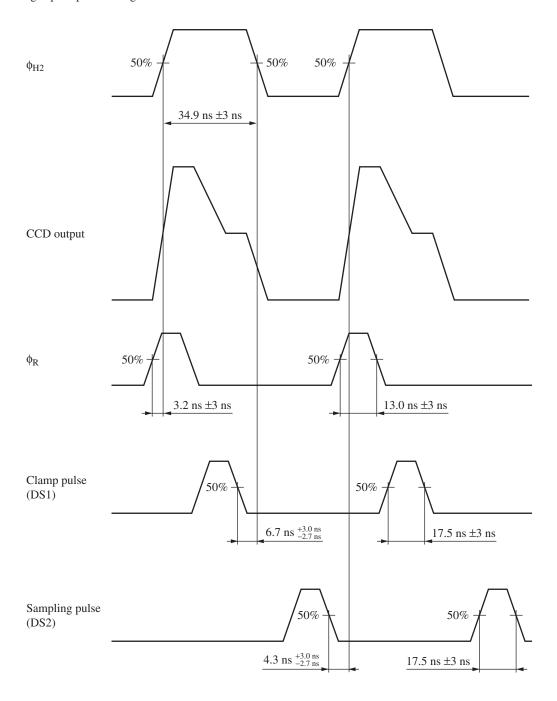
■ Graph of Characteristics

CCD color filter spectral characteristics



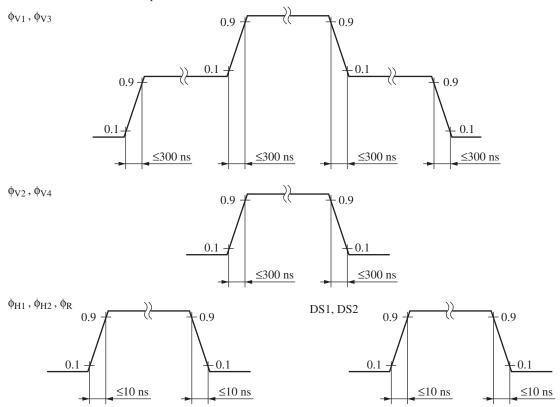
■ Timing Diagram

• High speed pulse timing

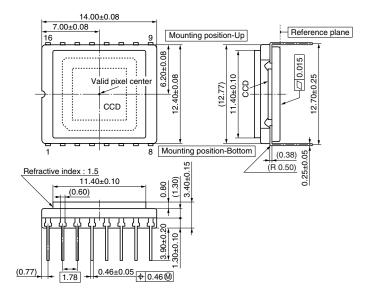


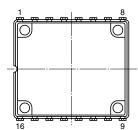
■ Timing Diagram (continued)

• Rise time and fall time of each pulse



- Package Dimensions (unit: mm)
- WDIP016-P-0500C





- 1. The center of the package is equal to the center of the effective pixel area.
- 2. The rotation angle of the effective pixel area: up to ± 1.0 degree
- 3. The distance from the bottom face of the package to the surface of the effective pixel area: 1.69 mm \pm 0.10 mm
- 4. The tilt of the effective pixel area for the bottom face of the package: up to 30 μm
- 5. Thickness of seal glass is $0.8 \text{ mm} \pm 0.10 \text{ mm}$, and the refractive index is 1.50.

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